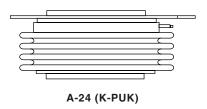


Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 2310 A



2310 A

PRODUCT SUMMARY

 $I_{T(AV)}$

FEATURES

- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case A-24 (K-PUK)
- High profile hockey PUK
- Lead (Pb)-free



TYPICAL APPLICATIONS

- · DC motor controls
- Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
		2310	А			
$I_{T(AV)}$	T _{hs}	55	°C			
		4150	А			
I _{T(RMS)}	T _{hs}	25	°C			
I _{TSM}	50 Hz	42 500	^			
	60 Hz	44 500	А			
121	50 Hz	9027	1.42-			
I ² t	60 Hz	8240	kA ² s			
V _{DRM} /V _{RRM}		400 to 600	V			
tq	Typical	200	μs			
TJ		- 40 to 125	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{DRM/} V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}I_{RRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= \text{T}_{J} & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$					
ST1280CK 04		400	500	100					
31 12000K	06	600	700	100					

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ST1280C..K Series

Phase Control Thyristors (Hockey PUK Version), Vishay High Power Products 2310 A



ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current		180° condu	ction, half sine v	vave	2310 (885)	Α
at heatsink temperature	I _{T(AV)}	Double side	Double side (single side) cooled		55 (85)	°C
Maximum RMS on-state current	I _{T(RMS)}	25 °C heats	ink temperature	double side cooled	4150	
		t = 10 ms	No voltage		42 500	A kA ² s
Maximum peak, one-cycle		t = 8.3 ms	reapplied		44 500	
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		35 700	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	37 400	
		t = 10 ms	ms reapplied	initial T _J = T _J maximum	9027	
Maximum 12t for fusing	l ² t	t = 8.3 ms			8241	
Maximum I ² t for fusing		t = 10 ms			6383	
		t = 8.3 ms	reapplied		5828	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10	ms, no voltage	reapplied	90 270	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.90	V
Low level value of on-state slope resistance	r _{t1}	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			0.077	m0
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.068	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 8000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.44	V
Maximum holding current	I _H	T of 90 and a sound of 0 V and diving the		600	mA	
Typical latching current I_L $T_J = 25$ °C, anode supply 12 V resistive load				z v resistive idau	1000	IIIA

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ V_{DRM}	1000	A/µs			
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 \ ^{\circ}C$	1.9	110			
Typical turn-off time t _q		$I_{TM} = 550 \text{ A, } T_J = T_J \text{ maximum, dI/dt} = 40 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V 100 }\Omega\text{, }t_p = 500 \mu\text{s}$	200	μs			

BLOCKING						
PARAMETER SYMBOL		TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs		
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	100	mA		

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TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	
PANAMETEN	STIVIBOL	STIMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	$t_p \leq 5 \; ms$	16		W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	3		VV
Maximum peak positive gate current	I _{GM}			3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum,	$t_p \leq 5 \; ms$	20		V
Maximum peak negative gate voltage	- V _{GM}			5	.0	v
		T _J = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest	200	-	mA
DC gate current required to trigger	I _{GT}	T _J = 25 °C		100	200	
		T _J = 125 °C		50	-	
		T _J = - 40 °C	value which will trigger all units	1.4	-	
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	12 V anode to cathode applied	1.1	3.0	V
		T _J = 125 °C		0.9	-	
DC gate current not to trigger	I _{GD}		Maximum gate current/voltage not to trigger is the maximum	10		mA
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	MBOL TEST CONDITIONS		UNITS	
Maximum operating temperature range	TJ	T _J		°C	
Maximum storage temperature range	T _{Stg}		- 40 to 150		
Maximum thermal resistance in nation to be stainly	0	DC operation single side cooled	0.042		
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.021	K/W	
Marian was the support resistance and the breathing	R _{thC-hs}	DC operation single side cooled	0.006		
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.003		
Mounting force, ± 10 %			24 500 (2500)	N (kg)	
Approximate weight			425	g	
Case style		See dimensions - link at the end of datasheet	A-24 (K-	PUK)	

△R _{thJC} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS	
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	OINITS	
180°	0.003	0.003	0.002	0.002			
120°	0.004	0.004	0.004	0.004	$T_J = T_J$ maximum		
90°	0.005	0.005	0.005	0.005		K/W	
60°	0.007	0.007	0.007	0.007			
30°	0.012	0.012	0.012	0.012			

Note

 $\bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{thJC} \, \text{when devices operate at different conduction angles than DC} \,$

Vishay High Power Products

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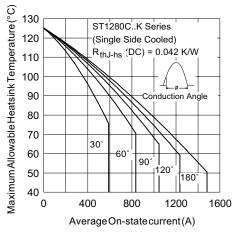


Fig. 1 - Current Ratings Characteristics

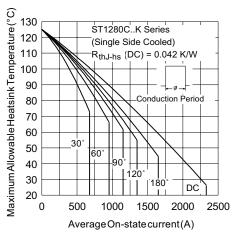


Fig. 2 - Current Ratings Characteristics

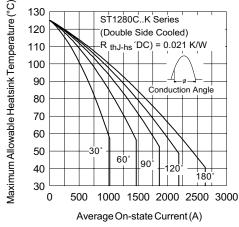


Fig. 3 - Current Ratings Characteristics

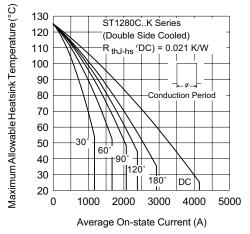


Fig. 4 - Current Ratings Characteristics

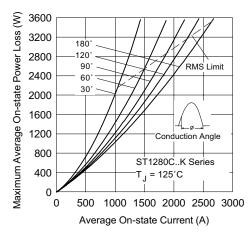


Fig. 5 - On-State Power Loss Characteristics

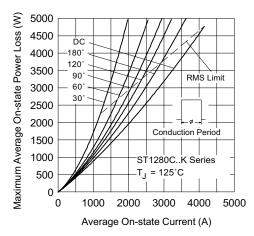
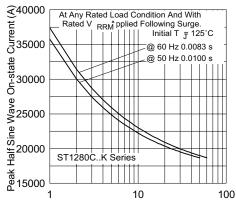


Fig. 6 - On-State Power Loss Characteristics



Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 2310 A



Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

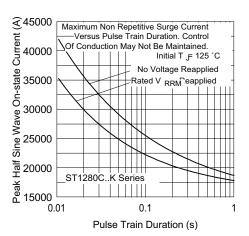


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

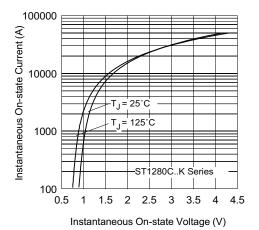


Fig. 9 - On-State Voltage Drop Characteristics

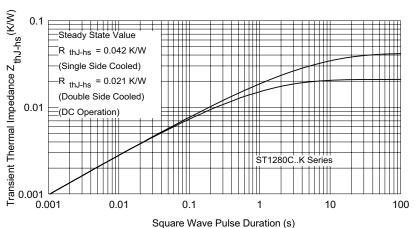


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

Vishay High Power Products **Phase Control Thyristors** (Hockey PUK Version), 2310 A



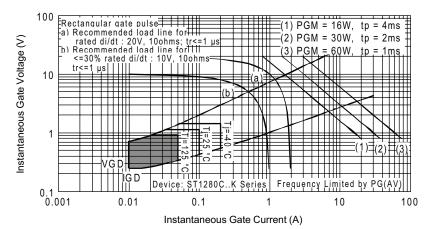
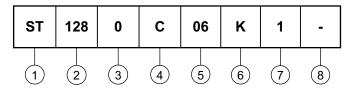


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



Thyristor

Essential part number

0 = Converter grade

C = Ceramic PUK

Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

K = PUK case A-24 (K-PUK)

0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = Eyelet terminals (gate and auxiliary cathode soldered leads)

3 = Fast-on terminals (gate and auxiliary cathode soldered leads)

8 Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

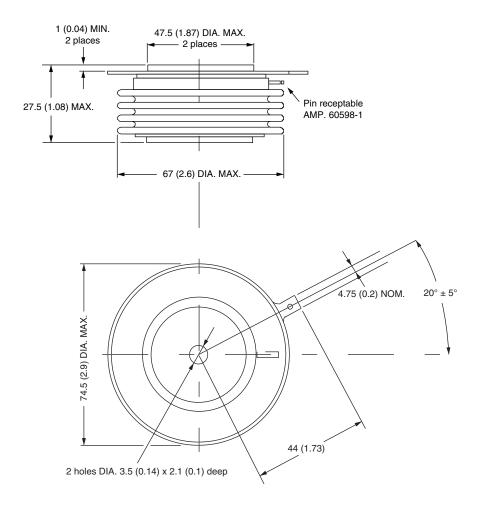
LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95081			

Vishay Semiconductors

A-24 (K-PUK)

DIMENSIONS in millimeters (inches)

Creepage distance: 28.88 (1.137) minimum Strike distance: 17.99 (0.708) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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